

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L3	113	((nonvolatile volatile flash) near memory) eeprom eprom rom) same (float\$6 near (gate electrode)) same ((interconnect\$6 line trace wir\$6 metal\$1i?ation) near4 (gate near2 (two second plural\$6 multiple))) same (select near (gate electrode))	US-PGPUB; USPAT	OR	ON	2007/02/28 10:11
L4	1	"7148104"	US-PGPUB; USPAT	OR	OFF	2007/02/28 10:11
L5	96	((nonvolatile volatile flash) near memory) eeprom eprom rom) same (float\$6 near (gate electrode)) same (etch\$6 with (liquid wet isotropic\$6)) same (isolation sti fox (field adj oxide) trench)	US-PGPUB; USPAT	OR	ON	2007/02/28 12:01
L6	79	((nonvolatile volatile flash) near memory) eeprom eprom rom) and (float\$6 near (gate electrode)) and ((interconnect\$6 line trace wir\$6 metal\$1i?ation) near4 (gate near2 (two second plural\$6 multiple)))	FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/02/28 10:58
L7	4566	438/259.ccls. 438/260.ccls. 438/261.ccls. 438/265.ccls. 438/266.ccls. 438/294.ccls. 438/296.ccls. 438/593.ccls. 257/e21.628.ccls. 257/e21.68.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2007/02/28 11:00
L8	159	L7 and (((nonvolatile volatile flash) near memory) eeprom eprom rom) same (float\$6 near (gate electrode)) same ((interconnect\$6 line trace wir\$6 metal\$1i?ation) with (gate near4 (two second plural\$6 multiple)))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2007/02/28 11:00
L9	585	438/266.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2007/02/28 11:14
L10	40	((nonvolatile volatile flash) near memory) eeprom eprom rom) and (float\$6 near (gate electrode)) and (etch\$6 with (liquid wet isotropic\$6)) and (isolation sti fox (field adj oxide) trench)	FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/02/28 11:26

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L12	34	L7 and (((nonvolatile volatile flash) near memory) eeprom eeprom rom) same (float\$6 near (gate electrode)) same (etch\$6 with (liquid wet isotropic\$6)) same (isolation sti fox (field adj oxide) trench))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2007/02/28 11:30
L13	183	(((nonvolatile volatile flash) near memory) eeprom eeprom rom) and (float\$6 near (gate electrode)) and ((interconnect\$6 line trace wir\$6 metal\$1i?ation) near4 (gate near2 (two second plural\$6 multiple))) and (gate cell electrode)).clm.	US-PGPUB	OR	ON	2007/02/28 11:37
L14	125	(((nonvolatile volatile flash) near memory) eeprom eeprom rom) and (float\$6 near (gate electrode)) and ((interconnect\$6 line trace wir\$6 metal\$1i?ation) near4 (gate near2 (two second plural\$6 multiple))) and (gate near2 (first second conduct\$6)) and cell).clm.	US-PGPUB	OR	ON	2007/02/28 11:40
L15	89	(((nonvolatile volatile flash) near memory) eeprom eeprom rom) and (float\$6 near (gate electrode)) and (etch\$6 with (liquid wet isotropic\$6)) and (isolation sti fox (field adj oxide) trench)).clm.	US-PGPUB	OR	ON	2007/02/28 12:04